

### FEATURES

- Large active area
- Photoconductive
- Low cost
- High speed

### DESCRIPTION

The **PDB-C158F** is a blue enhanced PIN silicon photodiode in a photoconductive mode with a daylight filter, packaged in a plastic sidelooker package.

### APPLICATIONS

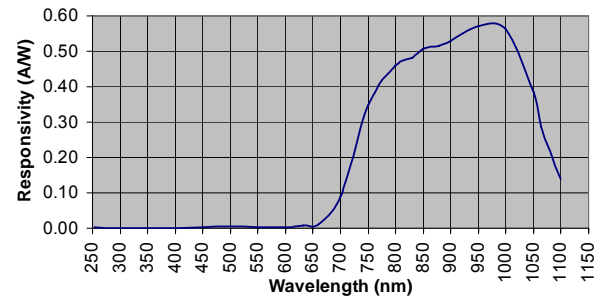
- Smoke detectors
- Light pen detectors
- TV & VCR remotes
- IR data links

### ABSOLUTE MAXIMUM RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	PARAMETER	MIN	MAX	UNITS
$V_{BR}$	Reverse Voltage		50	V
$T_{STG}$	Storage Temperature	-40	+100	°C
$T_O$	Operating Temperature	-40	+80	°C
$T_S$	Soldering Temperature*		+260	°C

\* 1/16 inch from case for 3 seconds max.

### SPECTRAL RESPONSE



### ELECTRO-OPTICAL CHARACTERISTICS RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$I_{SC}$	Short Circuit Current	H = 100 fc, 2850 K	100	145		$\mu A$
$I_D$	Dark Current	$V_R = 10 V$		2	30	nA
$R_{SH}$	Shunt Resistance	$V_R = 10 mV$	100	150		$M\Omega$
$C_J$	Junction Capacitance	$V_R = 10 V, f = 1 MHz$		10	25	pF
$\lambda_{range}$	Spectral Application Range	Spot Scan	700		1100	nm
$V_{BR}$	Breakdown Voltage	$I = 10 \mu A$	30	75		V
NEP	Noise Equivalent Power	$V_R = 10V @ \lambda = Peak$		$2.4 \times 10^{-14}$		$W/\sqrt{Hz}$
$t_r$	Response Time	$RL = 1 K\Omega, V_R = 10 V$		50		nS

\*\*Response time of 10% to 90% is specified at 660nm wavelength light.

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.